



BTA12

Preliminary

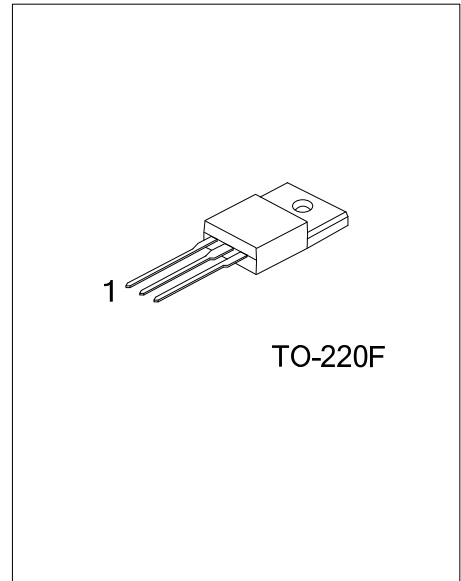
TRIAC

12A TRIACS

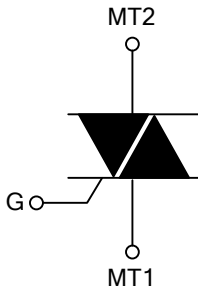
■ DESCRIPTION

The UTC **BTA12** is a 12A triacs, it uses UTC's advanced technology to provide customers with high commutation performances and voltage insulated tab, etc.

The UTC **BTA12** is suitable for inductive loads, general purpose AC switching and an ON/OFF function in applications such as motor speed controllers, induction motor starting circuits and static relays, etc.



■ SYMBOL



■ ORDERING INFORMATION

| Ordering Number | | Package | Pin Assignment | | | Packing |
|-------------------|-------------------|---------|----------------|-----|---|---------|
| Lead Free | Halogen Free | | 1 | 2 | 3 | |
| BTA12L-x-xx-TF3-T | BTA12G-x-xx-TF3-T | TO-220F | MT1 | MT2 | G | Tube |

| | |
|---|--|
| <p>BTA12L-x-xx-TF3-T</p> <p>(1)Packing Type (2)Package Type (3)Sensitivity and type (4)Voltage (5)Lead Free</p> | <p>(1) T: Tube (2) TF3: TO-220F (3) refer to SENSITIVITY AND TYPE (4) 6: 600V, 8: 800V (5) L: Lead Free, G: Halogen Free</p> |
|---|--|

■ SENSITIVITY AND TYPE

| PART NUMBER | VOLTAGE | | SENSITIVITY | TYPE |
|-------------|---------|------|-------------|-------------|
| | 600V | 800V | | |
| B | ⊙ | ⊙ | 50mA | STANDARD |
| BW | ⊙ | ⊙ | 50mA | SNUBBERLESS |
| C | ⊙ | ⊙ | 25mA | STANDARD |
| CW | ⊙ | ⊙ | 35mA | SNUBBERLESS |
| SW | ⊙ | ⊙ | 10mA | LOGIC LEVEL |
| TW | ⊙ | ⊙ | 5mA | LOGIC LEVEL |

⊙: Available

■ ABSOLUTE MAXIMUM RATINGS

| PARAMETER | | | SYMBOL | RATINGS | UNIT |
|---|---------|--|------------------------------------|---|------------------|
| RMS On-State Current (Full Sine Wave) | | T _C =90°C | I _{T(RMS)} | 12 | A |
| Non Repetitive Surge Peak On-State Current (Full Cycle, T _J initial=25°C) | F=50 Hz | t=20ms | I _{TSM} | 120 | A |
| | F=60 Hz | t=16.7ms | | 126 | A |
| I ² t Value for Fusing | | t _P =10ms | I ² t | 78 | A ² s |
| Critical Rate of Rise of On-State Current I _G =2xI _{GT} , t _r ≤100ns | | F=120 Hz T _J =125°C | di/dt | 50 | A/μs |
| Non Repetitive Surge Peak Off-State Voltage | | t _P =10ms T _J =25°C | V _{DSM} /V _{RSM} | V _{DRM} /V _{RRM} +100 | V |
| Peak Gate Current | | t _P =20μs T _J =125°C | I _{GM} | 4 | A |
| Average Gate Power Dissipation | | T _J =125°C | P _{G(AV)} | 1 | W |
| Operating Junction Temperature | | | T _J | -40~+125 | °C |
| Storage Junction Temperature | | | T _{STG} | -40~+150 | °C |

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL RESISTANCES

| PARAMETER | SYMBOL | RATINGS | UNIT |
|-----------------------|-----------------|---------|------|
| Junction to Ambient | θ _{JA} | 60 | °C/W |
| Junction to Case (AC) | θ _{JC} | 2.3 | °C/W |

■ ELECTRICAL CHARACTERISTICS (T_J=25°C unless otherwise specified)

FOR SNUBBERLESS TYPE and LOGIC LEVEL TYPE (3 QUADRANTS)

| PARAMETER | SYMBOL | TEST CONDITIONS | TW | | | SW | | | CW | | | BW | | | UNIT |
|--|----------------------|---|----------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|------|------|
| | | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | |
| SNUBBERLESS TYPE and LOGIC LEVEL TYPE (3 QUADRANTS) | | | | | | | | | | | | | | | |
| Gate Trigger Current (Note 1) | I _{GT} | V _D =12V, R _L =30Ω | I-II-III | | 5 | | | 10 | | | 35 | | | 50 | mA |
| Gate Trigger Voltage | V _{GT} | | I-II-III | | 1.3 | | | 1.3 | | | 1.3 | | | 1.3 | V |
| Gate Non-Trigger Voltage | V _{GD} | V _D =V _{DRM} , R _L =3.3kΩ, T _J =125°C | I-II-III | | 0.2 | 0.2 | | | | 0.2 | | | 0.2 | | V |
| Holding Current (Note 2) | I _H | I _T =100mA | | | | 10 | | | | 15 | | | 35 | | 50 |
| Latching Current | I _L | I _G =1.2I _{GT} | I-III | | 10 | | | 25 | | | 50 | | | 70 | mA |
| | | | II | | 15 | | | 30 | | | 60 | | | 80 | mA |
| Critical Rate of Rise of Off-State Voltage (Note 2) | dV/dt | V _D =67%V _{DRM} , Gate Open, T _J =125°C | | | 20 | | | 40 | | | 500 | | | 1000 | |
| Critical Rate of Rise of Off-State Voltage at Commutation (Note 2) | (di/dt) _C | (dV/dt) _C =0.1V/μs, T _J =125°C | | | 3.5 | | | 6.5 | | | | | | | |
| | | (dV/dt) _C =10V/μs, T _J =125°C | | | 1 | | | 2.9 | | | | | | | |
| | | Without Snubber T _J =125°C | | | | | | | | | 6.5 | | | 12 | |

Notes: 1. Minimum I_{GT} is guaranteed at 5% of I_{GT} max.
2. For both polarities of MT2 referenced to MT1.

■ ELECTRICAL CHARACTERISTICS(Cont.)

FOR STANDARD TYPE (4 QUADRANTS)

| PARAMETER | SYMBOL | TEST CONDITIONS | C | | | B | | | UNIT | |
|---|----------------------|--|----------|-----|-----|-----|-----|-----|------|------------|
| | | | MIN | TYP | MAX | MIN | TYP | MAX | | |
| Gate Trigger Current (Note 1) | I_{GT} | $V_D=12V, R_L=33\Omega$ | I-II-III | | | 25 | | | 50 | mA |
| | | | IV | | | 50 | | | 100 | mA |
| Gate Trigger Voltage | V_{GT} | | ALL | | | 1.3 | | | 1.3 | V |
| Gate Non-Trigger Voltage | V_{GD} | $V_D=V_{DRM}, R_L=3.3k\Omega, T_J=125^\circ C$ | ALL | 0.2 | | | 0.2 | | | V |
| Holding Current (Note 2) | I_H | $I_T=500mA$ | | | | 25 | | | 50 | mA |
| Latching Current | I_L | $I_G=1.2 I_{GT}$ | I-III-IV | | | 40 | | | 50 | mA |
| | | | II | | | 80 | | | 100 | mA |
| Critical Rate of Rise of Off-State Voltage (Note 2) | dV/dt | $V_D=67\%V_{DRM}, \text{Gate Open}, T_J=125^\circ C$ | | 200 | | | 400 | | | V/ μs |
| Critical Rate of Rise of Off-State Voltage at Commutation(Note 2) | (dV/dt) _c | (dI/dt) _c =5.3A/ms, $T_J=125^\circ C$ | | 5 | | | 10 | | | V/ μs |

■ STATIC CHARACTERISTICS

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------------------------|-----------|--|-----|-----|------|------------|
| Peak On-State Voltage(Note) | V_T | $I_{TM}=17A, t_p=380\mu s, T_J=25^\circ C$ | | | 1.55 | V |
| Threshold Voltage(Note) | V_{TO} | $T_J=125^\circ C$ | | | 0.85 | V |
| Dynamic Resistance(Note) | R_D | $T_J=125^\circ C$ | | | 35 | m Ω |
| Repetitive Peak Off-State Current | I_{DRM} | $V_{DRM}=V_{RRM}$ | | | 5 | μA |
| | I_{RRM} | | | | 1 | mA |

Note: 1. Minimum I_{GT} is guaranteed at 5% of I_{GT} max.
 2. For both polarities of MT2 referenced to MT1.

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